DOUT2 3

ROUT2 5

DIN2

ROUT1

RIN1

DIN1 7

6

8

9

П

GND 10

V_{CC} [11 C1+ [12

V+

C1-

П

13

14

RIN2 Π 4

DB, DW, OR PW PACKAGE

(TOP VIEW)

28 DOUT4

26 ROUT3

25 SHDN

24 🛛 EN

23 RIN4 22 ROUT4

21 DIN4

20 DIN3

18 RIN5

17 V-

16 C2-

15 C2+

19 ROUT5

27 RIN3

FEATURES

- ESD Protection for RS-232 Bus Pins – ±15-kV Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V V_{CC} Supply
- Four Drivers and Five Receivers
- Operates up to 120 kbit/s
- Low Supply Current in Shutdown Mode . . . 15 μA Typ
- External Capacitors . . . 4 × 0.1 F
- Designed to Be Interchangeable With Maxim MAX213
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

DESCRIPTION/ ORDER INFORMATION

The MAX213 device consists of four line drivers, five line receivers, and a dual charge-pump circuit with \pm 15-kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The devices operate at data signaling rates up to 120 kbit/s and a maximum of 30-V/µs driver output slew rate.

The MAX213 has an active-low shutdown (SHDN) and an active-high enable control (EN). In shutdown mode, the charge pumps are turned off, V+ is pulled down to V_{CC} , V– is pulled to GND, and the transmitter outputs are disabled. This reduces supply current typically to 1 μ A. Two receivers of the MAX213 are active during shutdown.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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ORDERING INFORMATION

T _A	PAC	KAGE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC – DW	Tube of 20	MAX213CDW	
0°C to 70°C	50IC - DW	Reel of 1000	MAX213CDWR	
		Tube of 50	MAX213CDB	
	SSOP – DB	Reel of 2000	MAX213CDBR	
	TSSOP – PW	Tape and reel	MAX213CPWR	
	SOIC – DW	Tube of 20	MAX213IDW	
	50IC - DW	Reel of 1000	MAX213IDWR	
–40°C to 85°C	SSOP – DB	Tube of 50	MAX213IDB	
	220h - DR	Reel of 2000	MAX213IDBR	
	TSSOP – PW	Tape and reel	MAX213IPWR	

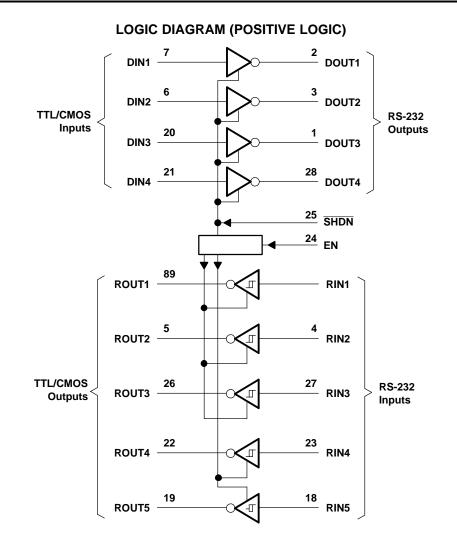
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

INP	UTS	DRIVER	REC	EIVER	DEVICE STATUS
SHDN	EN	D1–D4	R1–R3	R4–R5	DEVICE STATUS
L	L	Z	Z	Z	Shutdown
L	Н	Z	Z	Active ⁽¹⁾	Shutdown
Н	L	All active	Z	Z	Normal operation
Н	Н	All active	Active	Active	Normal operation

(1) See the V_{IT+} and V_{IT-} change in the *Electrical Characteristics* table.

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage range		-0.3	6	V	
V+	Positive charge-pump voltage range ⁽²⁾		V _{CC} – 0.3	14	V	
V–	Negative charge-pump voltage range ⁽²⁾	ve charge-pump voltage range ⁽²⁾		-14	V	
N/		Drivers	-0.3	V+ + 0.3	N/	
VI	Input voltage range	Receivers		±30	V	
	Drivers		V0.3	V+ + 0.3		
Vo	Output voltage range	Receivers	-0.3	V _{CC} + 0.3	V	
DOUT	Short-circuit duration		C	ontinuous		
		DB package		62		
θ_{JA}	Package thermal impedance ⁽³⁾⁽⁴⁾	DW package		46		
		PW package				
TJ	Operating virtual junction temperature	rating virtual junction temperature		150	C°	
T _{stg}	Storage temperature range		-65	150	C°	

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to network GND. (2)

Maximum power dissipation is a function of $T_J(max), \theta_{JA}$, and T_A . The maximum allowable power dissipation at any allowable ambient (3) temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

(4)

Recommended Operating Conditions⁽¹⁾

See Figure 4

			MIN	NOM	MAX	UNIT
	Supply voltage		4.5	5	5.5	V
v	Driver high-level input voltage DIN		2			V
V _{IH}	Control high-level input voltage	EN, SHDN	2.4			v
VIL	Driver and control low-level input voltage	DIN, EN, SHDN			0.8	V
v	Driver and control input voltage	DIN, EN, SHDN	0		5.5	V
VI	Receiver input voltage	RIN	-30		30	v
т	Operating free air temperature	MAX213C	0		70	°C
IA	Operating free-air temperature MAX213I		-40		85	C

(1) Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V \pm 0.5 V.

Electrical Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS			TYP ⁽²⁾	MAX	UNIT
I _{CC}	Supply current	No load,	See Figure 6		14	20	mA
I _{SHDN}	Shutdown supply current	$T_A = 25^{\circ}C$,	See Figure 1		15	50	μA

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V ± 0.5 V. (1)

(2) All typical values are at $V_{CC} = 5$ V, and $T_A = 25^{\circ}C$.

DRIVER SECTION

Electrical Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted) (see Figure 4)

PARAMETER		TEST CONDI	TEST CONDITIONS			MAX	UNIT
V _{OH}	High-level output voltage	DOUT at $R_L = 3 k\Omega$ to GNE)	5	9		V
V _{OL}	Low-level output voltage	DOUT at $R_L = 3 k\Omega$ to GNI	כ	-5	-9		V
I _{IH}	Control high-level input current	EN, <u>SHDN</u> = 5 V			3	10	μA
	Driver low-level input current	DIN = 0 V	DIN = 0 V		-15	-200	
ΙL	Control low-level input current	EN, <u>SHDN</u> = 0 V			-3	-10	μA
$I_{OS}^{(3)}$	Short-circuit output current	V _{CC} = 5.5 V,	$V_0 = 0 V$		±10	±60	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	$V_0 = \pm 2 V$	300			Ω

(1)

(2)

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V ± 0.5 V All typical values are at V_{CC} = 5 V, and T_A = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one (3) output should be shorted at a time.

Switching Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CO	NDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
	Maximum data rate	$C_L = 50 \text{ pF}$ to 1000 pF, One DOUT switching,					kbit/s
t _{PLH(D)}	Propagation delay time, low- to high-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 k\Omega$, See Figure 3		2		μs
t _{PHL(D)}	Propagation delay time, high- to low-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 k\Omega$, See Figure 3		2		μs
t _{sk(p)}	Pulse skew ⁽³⁾	$C_L = 150 \text{ pF}$ to 2500 pF, See Figure 3	$R_L = 3 k\Omega$ to 7 k Ω ,	300		ns	
SR(tr)	Slew rate, transition region (see Figure 2)	$C_L = 50 \text{ pF to } 1000 \text{ pF},$ $V_{CC} = 5 \text{ V}$	$R_L = 3 \ k\Omega$ to 7 $k\Omega$,	3	6	30	V/µs

(1)

(2)

Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as (t_{PLH} - t_{PHL}) of each channel of the same device. (3)

ESD Protection

over operating free-air temperature range (unless otherwise noted)

PIN	TEST CONDITIONS	TYP	UNIT
DOUT	Human-Body Model	±15	kV

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RECEIVER SECTION

Electrical Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST	TEST CONDITIONS			MAX	UNIT
V _{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	$I_{OH} = -1 \text{ mA}$				V
V _{OL}	Low-level output voltage	I _{OH} = 1.6 mA				0.4	V
V	Positive-going		Active mode		1.7	2.4	V
V _{IT+}	input threshold voltage	$V_{CC} = 5 V, T_A = 25^{\circ}C$	Shutdown mode (R4-R5)		1.5	2.4	v
V	Negative-going		Active mode	0.8	1.2		V
V _{IT}	input threshold voltage	$V_{CC} = 5 V, T_A = 25^{\circ}C$	Shutdown mode (R4-R5)	0.6	1.5		v
Vhys ⁽³⁾	Input hysteresis (V _{IT+} , V _{IT-})	$V_{CC} = 5 V$	$V_{CC} = 5 V$		0.5	1	V
r _l	Input resistance	$V_{CC} = 5 \text{ V}, \text{ T}_{A} = 25^{\circ}\text{C}$		3	5	7	kΩ
	Output leakage current	$EN = 0 V, 0 \le ROUT \le V$	/ _{CC} , R1–R3		±0.05	±10	μA

Switching Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS				TYP ⁽²⁾	MAX	UNIT
+	Propagation delay time,	C = 150 pc	See Figure 4	$\overline{\text{SHDN}} = V_{CC}$		0.5	10	
t _{PLH(R)}	low- to high-level output	C _L = 150 pF,	See Figure 4	<u>SHDN</u> = 0 V, R4–R5		4	40	μs
t _{PHL(R)}	Propagation delay time, high- to low-level output	C _L = 150 pF,	See Figure 4			0.5	10	μs
t _{en}	Output enable time	C _L = 150 pF,	See Figure 5			600		ns
t _{dis}	Output disable time	C _L = 150 pF,	See Figure 5			200		ns

Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C. (1)

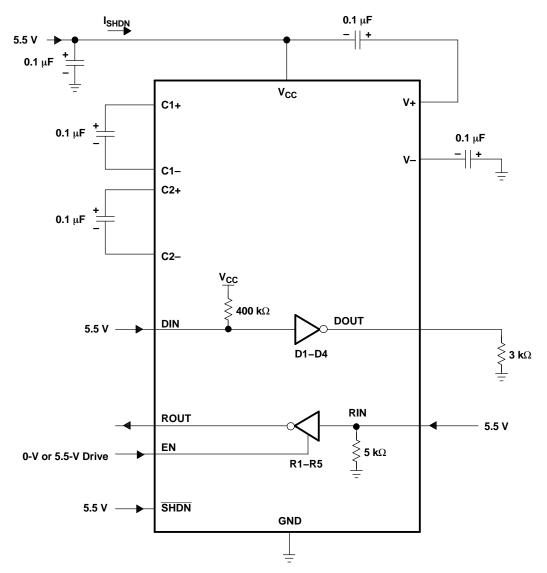
(2)

ESD Protection

over operating free-air temperature range (unless otherwise noted)

PIN	TEST CONDITIONS	TYP	UNIT
RIN	Human-Body Model	±15	kV

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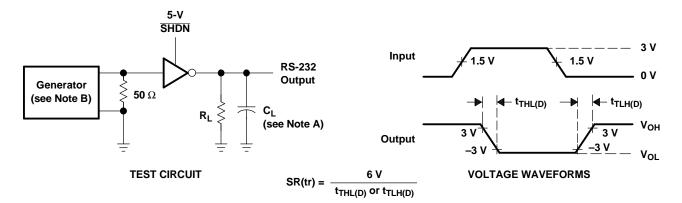
PARAMETER MEASUREMENT INFORMATION

Figure 1. Shutdown Current Test Circuit

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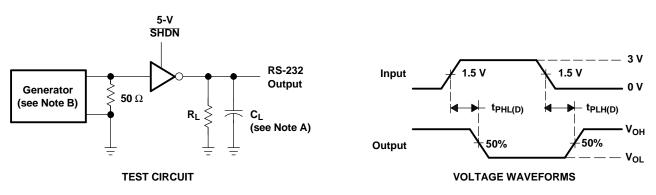
PARAMETER MEASUREMENT INFORMATION (continued)



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.

Figure 2. Driver Slew Rate



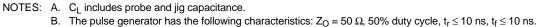
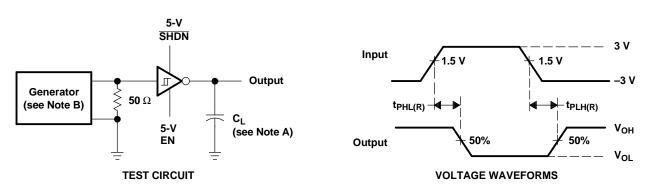


Figure 3. Driver Pulse Skew and Propagation Delay Times



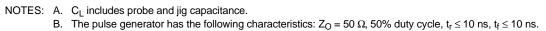
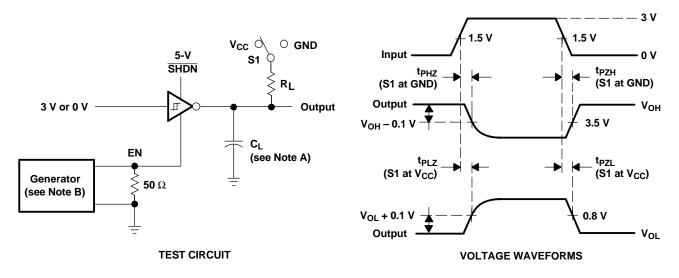


Figure 4. Receiver Propagation Delay Times



PARAMETER MEASUREMENT INFORMATION (continued)

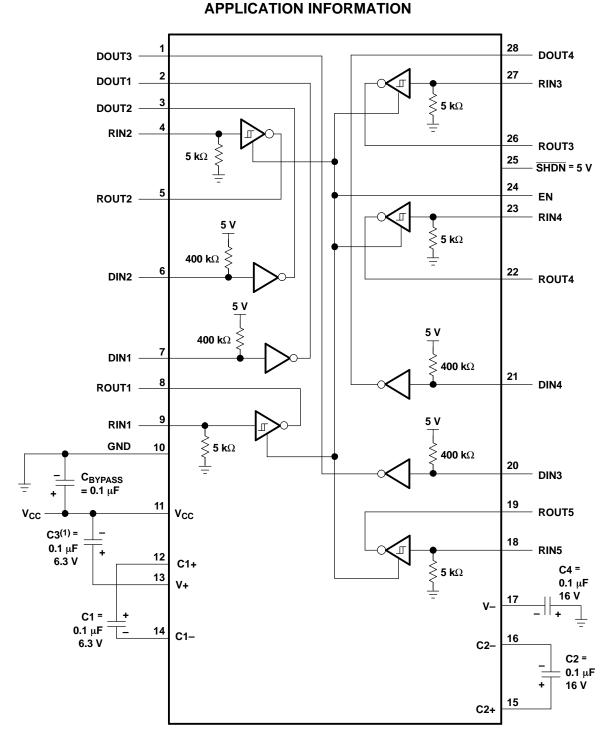


- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: $Z_0 = 50 \Omega$, 50% duty cycle, $t_r \le 10$ ns, $t_f \le 10$ ns.
 - C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - D. t_{PZL} and t_{PZH} are the same as t_{en} .

Figure 5. Receiver Enable and Disable Times

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(1) C3 can be connected to $V_{\mbox{CC}}$ or GND.

- NOTES: A. Resistor values shown are nominal.
 - B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MAX213CDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDW	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDWR	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDW	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDWR	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

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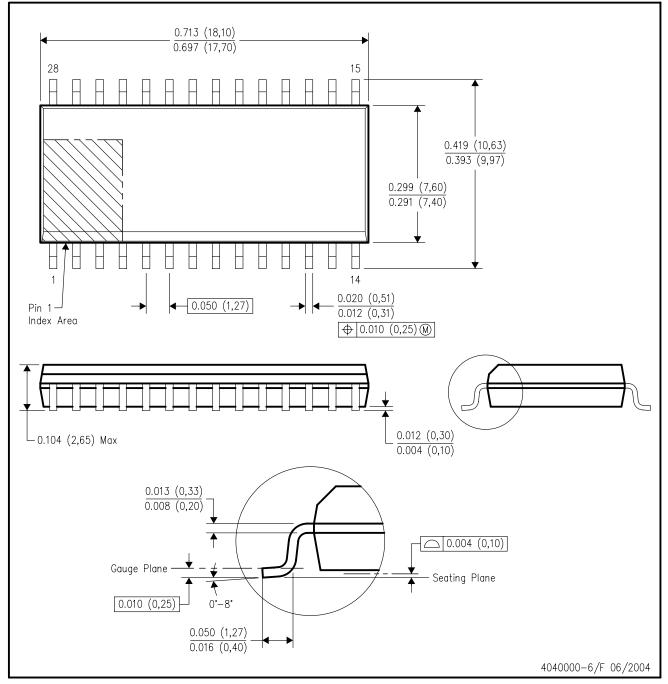
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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DW (R-PDSO-G28)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AE.



MECHANICAL DATA

MSSO002E - JANUARY 1995 - REVISED DECEMBER 2001

DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
- D. Falls within JEDEC MO-150



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